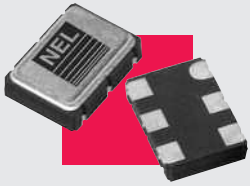


SD-A3670 Series



Size, mm
5 x 7
I/O
6 pad
Supply Voltage
3.3V

VCXO Series (PECL) SD-A3670 Series *Rev H* Frequency Range: 70.0 MHz to 200.0 MHz

Description

The **SD-A3670 Series** of voltage controlled quartz crystal oscillators provide frequency control by applying a voltage to Pin 1. This unit supplies DPECL compatible outputs which are enabled when Pin 2 is set to a logic low or left open.

Features

- Wide Absolute Pull Range
- High Reliability - NEL HALT/HASS qualified for crystal oscillator start-up conditions
- Low jitter - Wavecrest jitter characterization available
- Wide frequency range—70.0 MHz to 200.0 MHz
- User specified tolerance available
- Will withstand vapor phase temperatures of 253°C for 4 minutes maximum
- Space-saving alternative to discrete component oscillators
- High shock resistance, to 1000g
- 3.3 Volt operation
- Metal lid electrically connected to ground to reduce EMI
- High Q crystal actively tuned oscillator circuit
- Power supply decoupling internal
- No internal PLL avoids cascading PLL problems
- High frequencies due to proprietary design
- Gold plated pads
- RoHS Compliant, Lead Free Construction

Creating a Part Number

SD - A367X - FREQ

Package Code

SD 6 pad 5x7 mm SMD

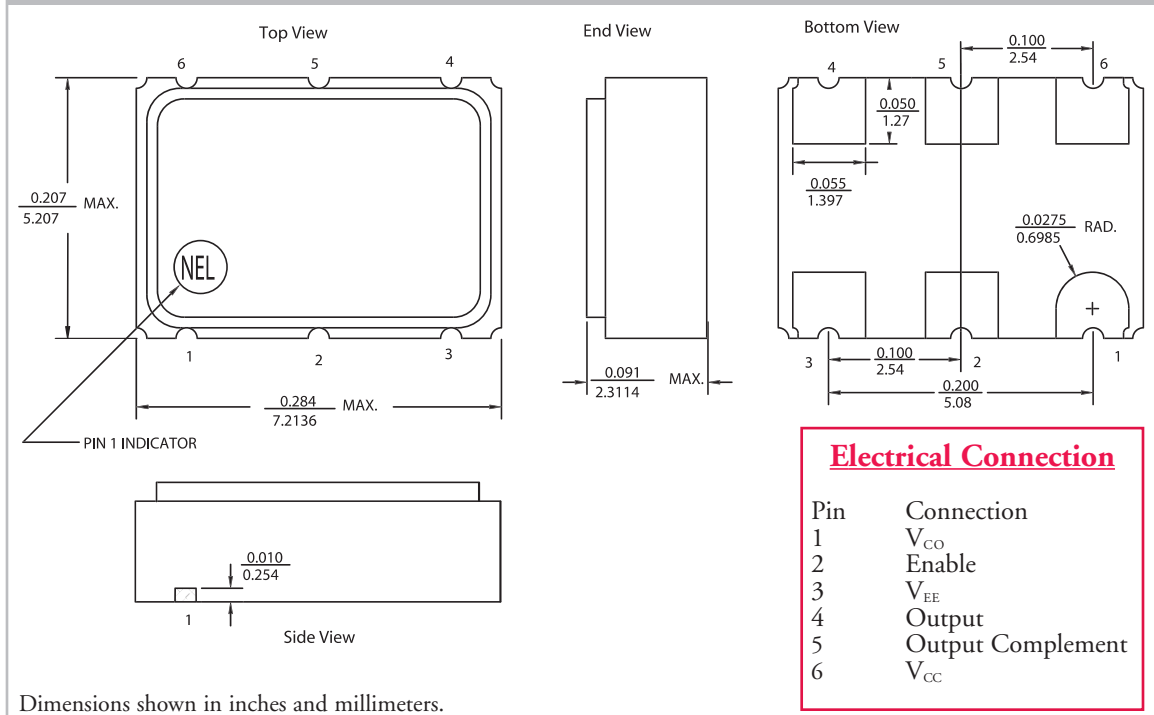
Input Voltage

Code Specification
A 3.3 V

Tolerance/Performance

0 ±100 ppm 0-70°C
9 Customer Specific
C ±100 ppm -40 to +85°C

Drawing Specifications



For the most up to date specifications on each NEL product, log on to our website—
www.nelfc.com

VCXO Series (PECL)

SD-A3670 Series *Rev H*

Frequency Range: 70.0 MHz to 200.0 MHz

Operating Conditions and Output Characteristics

Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max
Frequency	—	—	70.0 MHz	—	200.0 MHz
Duty Cycle	—	@V _o /2	45/55%	—	55/45%
Logic 0	V _{OL}	—	V _{CC} -1.810 V _{DC}	—	V _{CC} -1.620 V _{DC}
Logic 1	V _{OH}	—	V _{CC} -1.200 V _{DC}	—	V _{CC} -0.880 V _{DC}
Rise & Fall Time	t _r , t _f	20-80% V _o	—	—	600 ps
Jitter, RMS ⁽¹⁾	—	—	—	3 psec	—
Absolute Pull Range	APR	V _{CO} =0.3 to 3.0V	±100ppm	—	—
V _{CO} Input Impedance	—	50 na dc current max	100K ohm	—	—
V _{CO} Linearity	—	V _{CO} =0.3 to 3.0V	—	—	10%
Transfer Function ⁽²⁾	—	V _{CO} =0.3 to 3.0V	—	Positive	—

General Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max
Supply Voltage	V _{CC} -V _{EE}	Nominal	3.135 V	3.3 V	3.465 V
Supply Current	I _{CC}	—	—	—	60 mA
Output Current	I _O	—	0.0 mA	—	±50.0 mA
Operating Temperature	T _A	—	0°C	—	70°C
Storage Temperature	T _S	—	-55°C	—	125°C
Power Dissipation	P _D	—	—	—	208 mW
Lead Temperature	T _L	Soldering, 10 sec.	—	—	300°C
Load	50 ohm to V _{CC} -2 V or Thevenin Equivalent, Bias Required	—	—	—	—

Environmental and Mechanical Characteristics

Mechanical Shock	Per MIL-STD-202, Method 213, Condition E
Thermal Shock	Per MIL-STD-833, Method 1011, Condition A
Vibration	0.060" double amplitude 10 Hz to 55 Hz, 35g's 55 Hz to 2000 Hz
Soldering Condition	300°C for 10 seconds
Hermetic Seal	Leak rate less than 1 x 10 ⁻⁸ atm.cc/sec of helium

Footnotes:

- 1) Jitter performance is frequency dependent. Please contact factory for full Wavecrest characterization.
RMS jitter bandwidth of 12kHz to 20MHz.
- 2) Frequency increase with increase in control voltage and is monotonic.